

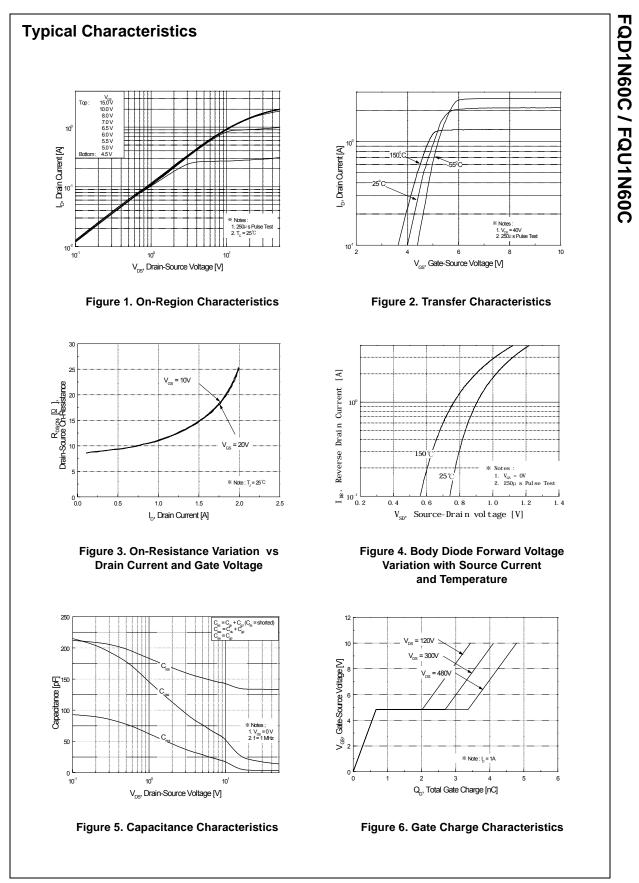
Symbol	Parameter		FQD1N60C / FQU1N60C	Units
V _{DSS}	Drain-Source Voltage		600	V
I _D	Drain Current - Continuous (T _C = 25°C))	1	А
	- Continuous (T _C = 100°C	C)	0.6	А
I _{DM}	Drain Current - Pulsed	(Note 1)	4	А
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	33	mJ
I _{AR}	Avalanche Current	(Note 1)	1	А
E _{AR}	Repetitive Avalanche Energy	(Note 1)	2.8	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.5	V/ns
	Power Dissipation (T _A = 25°C)*		2.5	W
PD	Power Dissipation ($T_C = 25^{\circ}C$)		28	W
	- Derate above 25°C		0.22	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

Thermal Characteristics

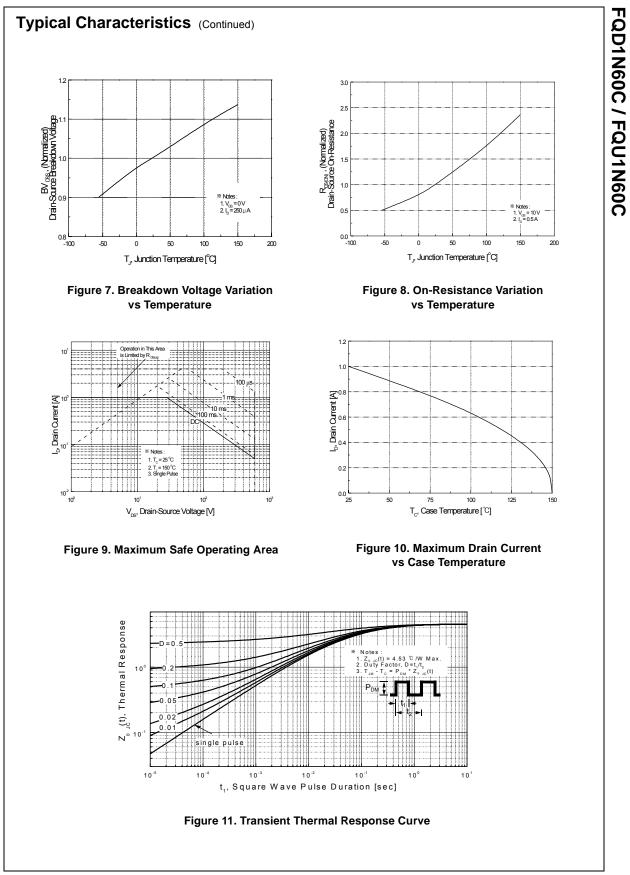
Symbol	Parameter	Тур	Max	Units
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case		4.53	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient*		50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		110	°C/W

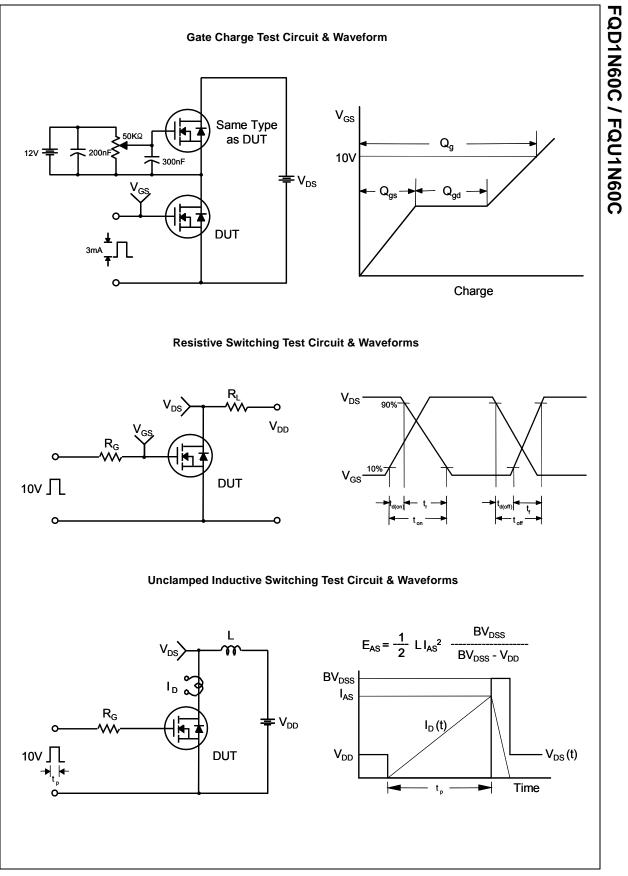
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	600			V
ΔBV _{DSS} / ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu$ A, Referenced to 25°C		0.6		V/°C
		V _{DS} = 600 V, V _{GS} = 0 V			1	μA
033	Zero Gate Voltage Drain Current	$V_{\rm DS} = 480 \text{ V}, \text{ T}_{\rm C} = 125^{\circ}\text{C}$			10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
GSSR	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
	racteristics	$\lambda = \lambda = 250$				
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V_{GS} = 10 V, I _D = 0.5 A		9.3	11.5	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 40 \text{ V}, \text{ I}_{D} = 0.5 \text{ A}$ (Note 4)		0.75		S
_						
	ic Characteristics					_
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		130	170	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		19	25	pF
C _{rss}	Reverse Transfer Capacitance			3.5	4.5	pF
Switchi	ng Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 300 V, I _D = 1.1 A,		7	24	ns
t _r	Turn-On Rise Time	$R_{G} = 25 \Omega$		21	52	ns
t _{d(off)}	Turn-Off Delay Time			13	36	ns
t _f	Turn-Off Fall Time	(Note 4, 5)		27	64	ns
Qg	Total Gate Charge	V _{DS} = 480 V, I _D = 1.1 A,		4.8	6.2	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		0.7		nC
Q _{gd}	Gate-Drain Charge	(Note 4, 5)		2.7		nC
	ource Diode Characteristics a	-				
ls	Maximum Continuous Drain-Source Dic				1	A
SM	Maximum Pulsed Drain-Source Diode F				4	A
V _{SD}	Drain-Source Diode Forward Voltage				1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 1.1 A,		190		ns
Q _{rr}	Reverse Recovery Charge	$dI_F / dt = 100 A/\mu s$ (Note 4)		0.53		μC
$\begin{array}{llllllllllllllllllllllllllllllllllll$	ating : Pulse width limited by maximum junction temper, I_{AS} = 1.1 A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 d/dt \leq 200A/µs, $V_{DD} \leq BV_{DSS}$, Starting T_J = 25°C Pulse width \leq 300µs, Duty cycle \leq 2% adependent of operating temperature					

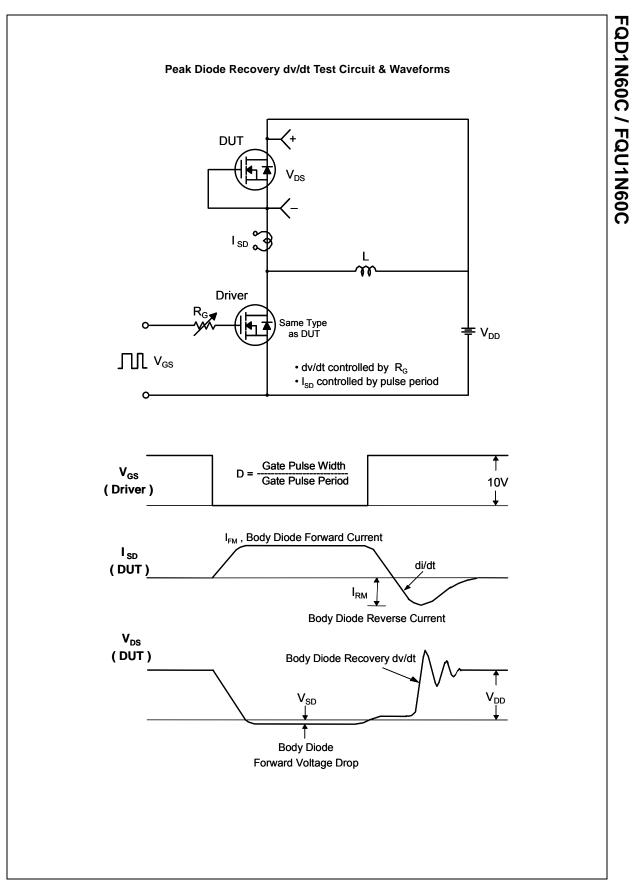
FQD1N60C / FQU1N60C

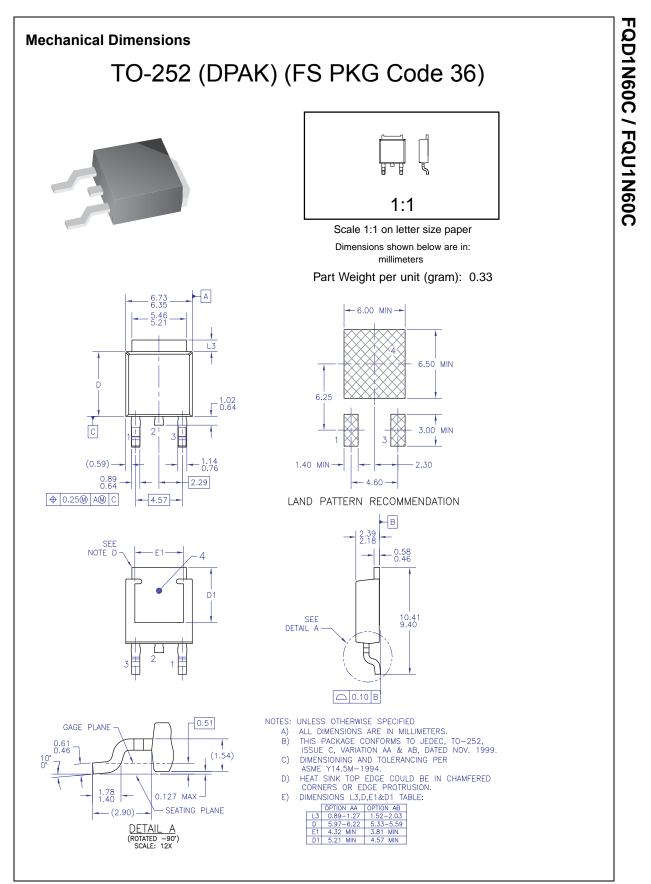


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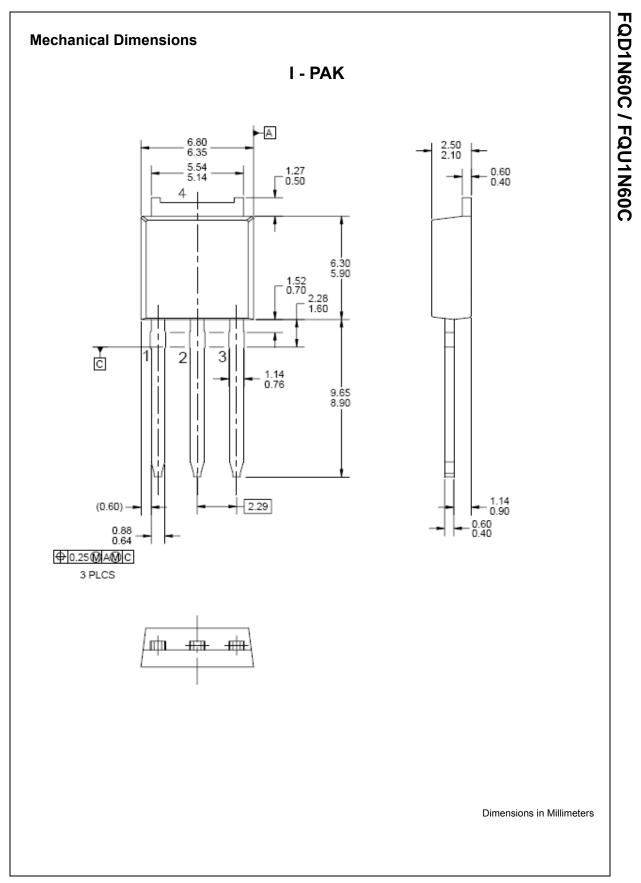








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